M etal-insulator transition and charge ordering in the extended H ubbard m odel at one-quarter lling

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(D ated: today)

W e study with exact diagonalization the zero tem perature properties of the quarter-led extended H ubbard m odel on a square lattice. W e nd that increasing the ratio of the intersite C oulom b repulsion, V, to the band width drives the system from a metal to a charge ordered insulator. The evolution of the optical conductivity spectrum with increasing V is compared to the observed optical conductivity of several layered m olecular crystals with the and $^{\circ0}$ crystal structures.

PACS num bers: 71.27+ a, 71.30+ h

Charge ordering in strongly correlated electron system s is currently under intense investigation. Charge ordering is relevant to a broad range of materials including the cuprates [1], manganates [2], magnetite [3], vanadium oxides [4], and the Bechgaard salts [5]. The and ⁽⁰⁾ types of layered molecular crystals based on molecules such as BEDT-TTF \models bisethylenedithio-tetrathiafulvalene] [6], display charge ordering, metallic, and superconducting phases close to each other [7]. Charge ordering driven by a strong inter-site C oulom b repulsion [8, 9] is possible in crystals with the and ⁽⁰⁾ arrangements of BEDT – TTF molecules because their bands are quarter–lled with holes, in contrast to the well studied -type, for which strong dimerization of the molecules lead to a half-</sup>

led band [10]. The -type crystals undergo a transition from a metal to a charge ordered insulator as the tem perature, pressure, uniaxial stress, or anion is varied [7, 8]. Furtherm ore, the metallic phase exhibits features characteristic of a strongly correlated system. In particular, the optical conductivity spectra display a broad mid-infrared band and a near absence of a D rude-like peak [11]. This is in contrast to conventionalmetals, for which the total spectral weight is dominated by a D rude peak.

In this Letter, we use the results of an exact diagonalization study of the relevant extended H ubbard m odel to argue that the inter-site C oulom b repulsion is responsible for the observed m etal-insulator transition in the and

 $^{\circ\circ}$ crystals. W e show how the D rude weight decreases as the inter-site C oulom b repulsion, V, is increased, until, at a nite value of V, a transition to an insulating phase occurs. Simultaneously, long range charge ordering gradually sets in. W e further nd that a redistribution of the optical conductivity spectra occurs close to the m etalinsulator transition. This nding is in qualitative agreement with experimental data on and $^{\circ\circ}$ organic salts [1, 12, 13, 14].

The quarter-led extended Hubbard model on a square lattice is the simplest strongly correlated model that can potentially describe the competition between m etallic, superconducting, and insulating phases in the and 00 m aterials [15, 16]. The Ham iltonian is

$$H = t X (c_{i}^{y} c_{j} + c_{j}^{y} c_{i}) + U X n_{i^{*}} n_{i\#}$$

$$+ V n_{i} n_{j}$$

$$< ij>$$

$$(1)$$

where c_i^y creates an electron of spin at site i. For V = 0, previous calculations suggest that the system is metallic with no charge order [17]. In the limit of U;V t the double occupation of sites is suppressed and the ground state is insulating with checkerboard charge ordering and long range antiferrom agnetic correlations along the diagonals [15].

In the present work we consider large (but nite) U=t and vary V=t [18]. Previously, an SU (N) generalisation of the model with U ! 1, was studied in the large N $\lim it using slave bosons[15, 16]$. It was found that as V=t increased there was a transition from a metallic phase to a superconducting phase (with d_{xy} symmetry) to a charge ordered phase. Given this potentially rich phase diagram it is in portant to determ ine whether or not these previous results are an artefact of the approxin ations used or whether they re ect the actual physics (N = 2 and nite U = t). Exact diagonalization of small system s provides such a test. P reviously, sim ilar m odels with more parameters, aim ed at a more realistic description of the details of the materials, have been studied by Hartree-Fock [9], and quantum Monte Carlo [19], and exact diagonalization [20]. W e perform ed a Lanczos calculation on L = 8;16;20 site clusters[17] avoiding uncompensated spin moments in the cluster (N $_{\rm H}$ = N $_{\rm \#}$) at quarter-lling: < n > = 1=2. A powerful method to determ ine from small systems whether the bulk system is m etallic or insulating is to evaluate the D rude weight

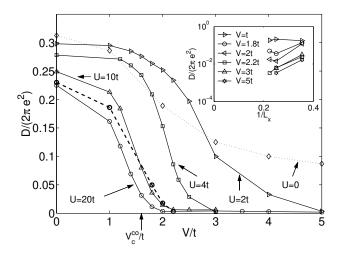


FIG. 1: M etal-insulator transition induced by the nearestneighbour C oulom b interaction V. The D rude weight, D, is shown as a function of V=t, for L = 16 and various values of U=t (continous and dotted lines) and for L = 20, U = 10t (dashed line). The arrow in the horizontal axis marks the onset of checkerboard charge ordering at V = V_c^{CO} , for U = 10t (see Fig. 2). The inset shows the nite-size scaling of D as a function of 1=L_x for di erent values of V=t with U = 10t. The m etal-insulator transition occurs at V_c^{MI} 2.2t.

D [21, 22, 23]. It is given by

$$\frac{\mathrm{D}}{\mathrm{2} \mathrm{e}^2} = \frac{\mathrm{h0}\mathrm{fr}\,\mathrm{jh}}{\mathrm{4L}} \frac{1}{\mathrm{L}} \frac{\mathrm{X}}{\mathrm{L}} \frac{\mathrm{jn}\,\mathrm{jj}_{\mathrm{x}}\,\mathrm{pij}_{\mathrm{f}}}{\mathrm{E}_{\mathrm{n}} \mathrm{E}_{\mathrm{0}}}$$
(2)

where E_0 and E_n , denote the ground state and excited state energies of the system, respectively. T is the kinetic energy operator and j_x is the current operator in the x direction at zero wavevector (q = 0). The occurrence of an insulating phase is marked by the exponential vanishing of D with the linear size of the system $L_x = \frac{1}{L}$ [22, 23, 24].

In Fig. 1 we plot the D rude weight as a function of $V = t_r$ for L = 16 and di erent values of U=t. For U = 10t we also plot the D rude weight for the cluster with L = 20. As the Coulomb nearest-neighbors repulsion is gradually increased, the D rude weight decreases until it eventually vanishes. For L = 16 we estim ate the critical value for the metal-insulator transition to be $V_{\rm c}^{\rm M~I}$ 2:2t; for this value, the D rude weight becom es of the order of 10 3 and stays of this order up to V = 5t. For L = 20 we do not nd any signi cant change in the dependence of the D rude weight with V, meaning that the nite size e ects in the Drude weight are weak. This is con med in the inset of Fig. 1 which shows the nite-size scaling of the D rude weight. Indeed, we distant for $V > V_{n}^{M I}$ 2:2t, the D rude weight displays an exponential dependence with $1=L_x$, as expected for an insulator[22, 23]. It extrapolates to values of the order of 10 5 in the therm odynam ic lim it. In contrast, for $V < V_c^{M I}$, the D rude weight is weakly dependent on $1=L_x$ extrapolating to a

nite value in the therm odynam ic lim it, consistent with a m etallic state.

The occurrence of charge ordering can be investigated by computing the charge correlation function

$$C(q) = \frac{1}{L} \sum_{ij}^{X} e^{iq (R_i R_j)} < n_i n_j >$$
(3)

where q are the allowed m om enta on the cluster. We nd that at V = 0, C (q) is featureless. As V is increased, C (q) peaks at q = Q(;), signalling checkerboard charge ordering. In our calculations we do not nd any evidence for other charge ordering patterns, such as those found in References [9, 20]. The system has long range charge ordering if C (Q) remains nite in the therm odynam ic lim it. In Fig. 2 we plot C (Q) as a function of 1=L. A linear dependence with 1=L is expected for the nite size scaling of an order param eter with a discrete sym metry in two dimensions [25]. For V = 0, we observe that the linear extrapolation of C (Q) (using L = 16;20) to the in nite volum e lim it tends to zero, i.e., the charge is homogeneously distributed in the lattice. We nd that the extrapolation of a linear t of L = 8;16;20 to the thermodynamic limit becomes nite at about $V_c^{C\,O}$ 1**:**6t [26]. If we decrease U the critical value $V_{\rm c}^{\,C\,0}$ increases. This is because doubly-occupied sites proliferate so that inducing the checkerboard charge ordered state becom es energetically less favorable. Further insight into the transition can be obtained by computing the charge order-C (Q) = < n^2 > . A non-zero ing param eter[27], = m eans long range charge ordering. In particular, for

= 1 the checkerboard charge ordered state is fully form ed, while for = 0 the charge is hom ogeneously distributed in the lattice. At V = 2.2t we nd that the checkerboard is close to being completed, 0:75. We note that the results we nd here are di erent from the ones obtained in two-leg ladders [27] where a transition from an hom ogeneous insulating phase to a charge ordered insulating phase takes place. This di erence is due to the one-dimensional nature of the two-leg ladder.

At this stage we can provide a physical interpretation of our ndings. Only when V is su ciently large so that the checkerboard charge ordered state is nearly completed, a transition to an insulating state is possible. This is because moving an electron within the checkerboard ordered state would cost an energy of 3V, which is comparable to the bandwidth, W = 8t. As a consequence electrons can becom e localized. As an aside we note that Fig. 1 shows that increasing U from 10t to 20t, leads to only a slight decrease in the critical value, $V_c^{M I}$. This contradicts the results obtained by 0 hta et al. [28] who claim that V_c U=4.W e note that the critical value $V_{c}^{M I}$ for large U follows the tendency encountered in onedim ensional rings [29] and two-leg ladders [27] for which $V_{\rm c}^{\,{\rm M}~{\rm I}}$ decreases to 2t as U $\,!\,$ 1 .

Since we nd that $V_c^{M I} > V_c^{C O}$, it might be possible that a charge ordered metallic state is realized

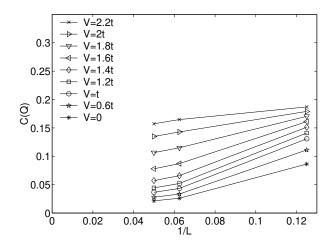


FIG.2: Checkerboard charge ordering induced by the nearest neighbour C oulom b interaction. Finite-size scaling of the charge correlation function C (q) (de ned in Eqn. (3)) at q = Q (;) for U = 10t and several values of V=t at quarter lling. Long range checkerboard charge ordering occurs for V > V_c^{CO} 1:6t.

in the range: $V_c^{CO} < V < V_c^{MI}$. However, caution is in order because the form er value is quite sensitive to nite-size e ects. A possible candidate for this phase is the quarter-lled organic crystal: "-(BEDT-TTF)_2SF_5CH_2CF_2SO_3, which displays metallic behavior of the resistivity and at the same time charge disproportion in alternate molecules[30].

In order to further our understanding of the m etalinsulator transition and m ake contact with experiments on and 00 m aterials, we have also computed the real part, (!), of the optical conductivity [31] at frequency !,

$$(!) = D \quad (!) + \frac{e^2}{L} \frac{X}{E_n \in 0} \frac{\ln j \ln j \ln j \ln 2}{E_n E_0} \quad (! \quad E_n + E_0):$$
(4)

It obeys the following sum rule [32]

$$Z_{1}$$
 (!)d! = $\frac{e^{2}}{2L} < 0 \text{ fr } \text{ p} > :$ (5)

In Fig. 3 we plot the evolution of the optical conductivity for di erent values of V=t and L = 20. We also found that the plots were qualitatively similar for L = 16 (not shown). For the regular Hubbard model, i.e. V = 0 (Fig. 3 (a)), there are two features at non-zero frequency. The highest energy feature is related to transitions associated with the Hubbard bands and the other is the \m id-infrared" band, previously found by D agotto et al.[21]. At V = 1.8t (Fig. 3 (b)), the D rude peak is reduced (see Fig. 1), signalling the incipient localization of the charge carriers. Spectral weight is transferred from

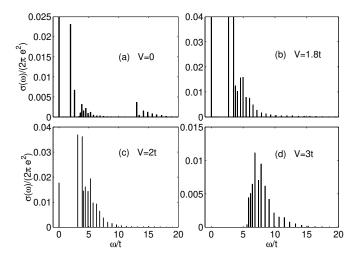


FIG.3: Transfer of spectral weight in the optical conductivity with increasing V=t. The frequency dependence of the real part of the conductivity (!) for L = 20 and U = 10t is shown in both the metallic [V = 0 (a), V = 1.3t (b), V = 2t (c)], and insulating [V = 3t (d)] phases. Note that close to the metal-insulator transition the spectral weight from the D rude peak and the H ubbard feature is transferred to the $\mbox{mid-infrared}$ " peak.

both the Hubbard feature and the D rude peak to them idinfrared band found at V = 0. This e ect is more clearly observed for V = 2t in Fig. 3 (c): the D rude peak is further suppressed and most of the spectral weight appears at low frequencies, in the range V < ! < 3V. Increasing V further to just below $V_{M I}$ gives a similar shape of the optical conductivity (not shown) with a very sm all D rude weight. Finally, Fig. 3 (d) shows the optical conductivity on the insulating side of the transition: V = 3t. An optical gap opens and most of the spectral weight concentrates at larger frequencies building up a single broad resonance. If V is further increased, V >> U=4, then the band associated with charge excitations due to V appears above the Hubbard band situated near ! U,as discussed by O hta et al. [28]. In sum m ary, Fig. 3 shows that close to the metal-insulator transition the optical conductivity is dom inated by the "m id-infrared" feature, for both m etallic and insulating phases. W e now discuss how this is what is observed in the and 00 m aterials.

The optical conductivity we nd close to the metal-insulator transition, V $^{<}$ $V_{c}^{M I}$, is qualitatively similar to the optical conductivity of $^{\circ\circ}$ -(BEDT-TTF)₂SF₅CH₂CF₂SO₃, measured by Dong et al. [11] (at a temperature, T = 14 K). Indeed, the small spectral weight at zero frequency found here is consistent with their failure to observe a D rude peak, even though the system is metallic. A leo their observation of large spectral weight at low frequencies is consistent with the mid-infrared band we nd in our calculations. At V $^{<}$ $V_{c}^{M I}$, the system is still on the metallic side of the metal-insulator transition which is con-

sistent with the observed metallic behavior of the resistivity. From the above discussion we conclude that $^{O}-$ (BEDT-TTF)₂SF₅CH₂CF₂SO₃ is a metal close to a metal-insulator transition. This assertion is corroborated by the fact that an external perturbation, such as a magnetic eld[33] or pressure[34], or replacing the anion CH₂CF₂ by CH₂ [35], drives the system into an insulating phase.

Optical conductivity measurements on the -type crystals all show a broad feature from around 1000 to 5000 om ¹ [12, 13, 14, 36]. We assign this to the "midinfrared" band. We now compare this interpretation to previous work. -(BEDT-TTF)₂CsZn(SCN)₄, is a metal above 20 K and an insulator below 20 K. The frequencydependent conductivity from 650 to 5000 cm 1 at tem peratures above 20 K shows a feature from 650 to about 1200 cm⁻¹ [12], which Tajim a et al. assigned to a D rude peak, with a phenom enological dam ping rate of 0.1 eV ' 800 cm 1 . -(BEDT-TTF)₂I₃ is a metalwhich undergoes a transition to a superconductor at 3.6 K. Tam ura et al. [36] m easured the optical conductivity from about 700 to 4000 cm 1 in the metallic phase. They assign the spectrum below about 1000 cm ¹ to the tail of a D rude peak with a phenom enological dam ping rate of 400 to 800 ${\rm cm}^{-1}$, depending on the tem perature. W e disagree with the assignment of these low energy features to a D rude peak because it requires large scattering rates, com parable to t, implying a \bad" metal. In the materials the observed widths of the D rude peak (and thus the scattering rate) at low tem peratures are orders of m agnitude smaller than this, typically of the order of tens of cm 1 [37]. We would assign all of the spectrum observed for $-(BEDT-TTF)_2 I_3$ [36] to the "m id-infrared" band. The experiment of Tamura et al.[36] did not go to low enough frequencies to observe the actual D rude peak. The feature in -(BEDT-TTF)₂CsZn(SCN)₄ that Tajim a et al. [12] assigned to a D rude peak we would assign to a phonon (and possibly its interference with the tail of the "mid-infrared" band) for the following reason. The optical conductivity spectrum of -(BEDT-TTF)₂RbCo(SCN)₄ was studied in detail by Tajim a et al.[12]. Thism aterial becom es a charge ordered insulator below 190 K. In slowly cooled samples the only signi cant spectral weight below 2000 cm⁻¹ is a phonon around 1200 cm 1 (com pare Fig. 5(a) in Ref. 12). If the sample is quenched (i.e., rapidly cooled) there is a broad feature around this frequency. In the organics such quenching is usually associated with signi cant amounts of disorder [38].

Tajim a et al. [12] assigned the second broad feature extending from above about 1200 cm 1 to dom ains associated with the onset of charge ordering. This was based on the calculated optical conductivity for a mean-eld solution of the extended Hubbard model. A lthough we have essentially the same assignment as theirs for the "mid-infrared" band we note that theirm ean-eld calculation cannot actually produce this feature in the m etallic phase. This underscores the m any-body physics underlying this feature and the need for our exact diagonalization calculation.

W e suggest two possible reasons for the absence of the Hubbard resonance in the experimental spectra. First, Fig. 3 (c) and (d) suggest that most of the spectral weight from it is transferred to the "mid-infrared" band Second, it could be at a frequency above the range of the experiments. The most reliable estimates put U V ' 0.5 eV ' 4000 cm⁻¹ [18]. If V ' 2t 0.1 eV [15], Fig. 3 (c) would put the mid-infrared band extending from about 1000 cm⁻¹ to 4000 cm⁻¹ and the Hubbard band feature roughly around 6000 cm⁻¹. The latter is near the edge of many of the experimental plots.

In summary, we have shown that increasing the nearest-neighbors $C\,{\rm ou}\,lom\,\,b$ repulsion, V , for the quarter-

led extended Hubbard model on the square lattice, leads to an insulating phase for V > 2:2t. The calculated optical conductivity spectra close to the metal-insulator transition is consistent with experimental data on several and ⁽⁰⁾- type molecular crystals. At V $V_c^{M~I}$, the D rude peak is strongly supressed and the spectral weight is dominated by a broad "mid-infrared" band associated with short-range charge ordering.

W e thank O.G unnarsson for making available his exact diagonalization code, E.K och, M.C apone, F.Becca, M.D ressel, and M.B runner for very helpful discussions, and the Max-Planck-Forschungspreis for nancial support.JM.was supported by a Marie Curie Fellow ship of the European Community program me "Improving Human Potential" under contract No. HPM F-CT-2000-00870 and R.H.M. by the Australian Research council.

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